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**CONTINUING DATA VERIFIED:					
**FOREIGN APPLICATIONS VERIFIED:					
PG-PUB DO NOT PUBLISH <input type="checkbox"/>			RESCIND <input type="checkbox"/>		
Foreign priority claimed <input type="checkbox"/> yes <input type="checkbox"/> no 35 USC 119 conditions met <input type="checkbox"/> yes <input type="checkbox"/> no Verified and Acknowledged Examiner's initials			ATTORNEY DOCKET NO. LIN 11-34		
TITLE : Semiconductor device having a doped lattice matching layer and a method of manufacture therefor.					

U.S. DEPT. OF COMMERCE PAT. & TRADEMARK OFFICE (Rev. 12-24)

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